

PNP General Purpose Amplifier

This device is designed for general purpose amplifier applications at collector currents to 300 mA. Sourced from Process 73.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CES}	Collector-Emitter Voltage	80	V	
V _{CBO}	Collector-Base Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	4.0	V	
Ic	Collector Current - Continuous	500	mA	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations. 3) All voltages (V) and currents (A) are negative polarity for PNP transistors.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Мах		Units	
		MPSA56	*MMBTA56	**PZTA56	
PD	Total Device Dissipation	625	350	1,000	mW
	Derate above 25°C	5.0	2.8	8.0	mW/∘C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

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(continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	80		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	80		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \ \mu A, \ I_C = 0$	4.0		V
I _{CEO}	Collector-Cutoff Current	$V_{CE} = 60 \text{ V}, \text{ I}_{B} = 0$		0.1	μΑ
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 80 \text{ V}, I_E = 0$		0.1	μΑ

h _{FE}	DC Current Gain	$I_{C} = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$	100		
		I _C = 100 mA, V _{CE} = 1.0 V	100		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	$I_{\rm C}$ = 100 mA, $V_{\rm CE}$ = 1.0 V		1.2	V

SMALL SIGNAL CHARACTERISTICS

f _T Current Gain - Bandwidth F	duct $I_{c} = 100 \text{ mA}, V_{cE} = 1.0 \text{ V},$ f = 100 MHz	50	MHz
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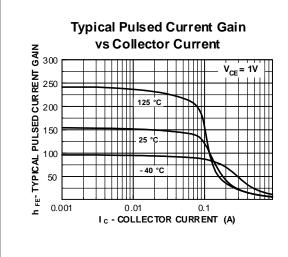
*Pulse Test: Pulse Width ${\leq}\,300\,\mu\text{s},$ Duty Cycle ${\leq}\,2.0\%$

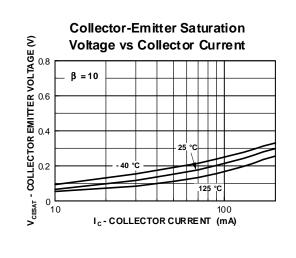
 $\textbf{NOTE:} \ \textbf{All voltages} \ (V) \ \textbf{and} \ \textbf{currents} \ (A) \ \textbf{are negative polarity for PNP transistors}.$

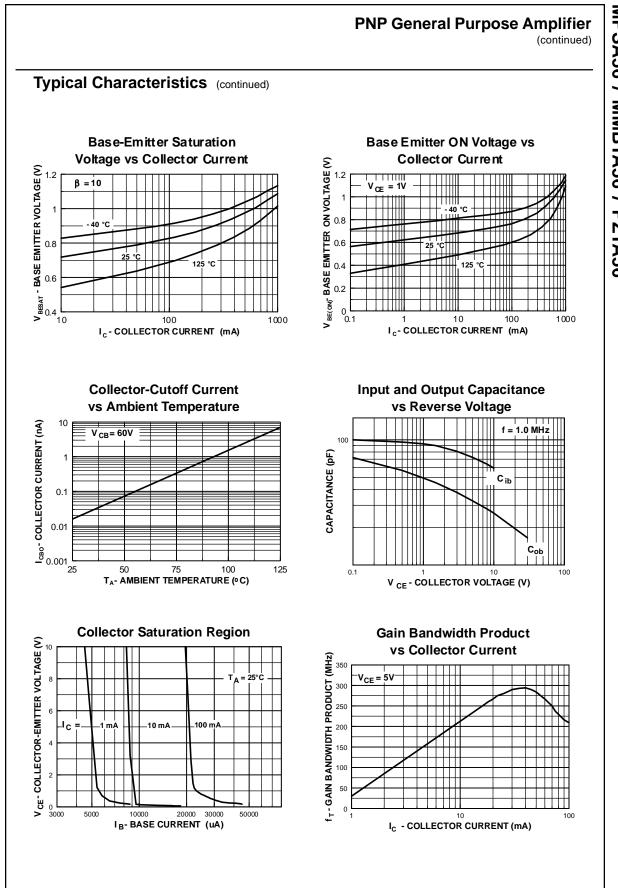
Spice Model

PNP (Is=12.27p Xti=3 Eg=1.11 Vaf=100 Bf=91.63 Ne=1.531 Ise=12.27p Ikf=1.009 Xtb=1.5 Br=1.287 Nc=2 Isc=0 Ikr=0 Rc=.6 Cjc=48.28p Mjc=.5615 Vjc=.75 Fc=.5 Cje=106.7p Mje=.5168 Vje=.75 Tr=496.3n Tf=865.8p Itf=.2 Vtf=2 Xtf=.8 Rb=10)

Typical Characteristics



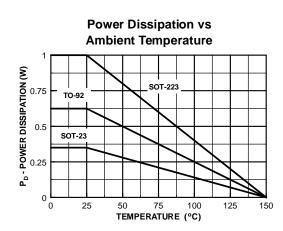




MPSA56 / MMBTA56 / PZTA56

PNP General Purpose Amplifier (continued)





MPSA56 / MMBTA56 / PZTA56



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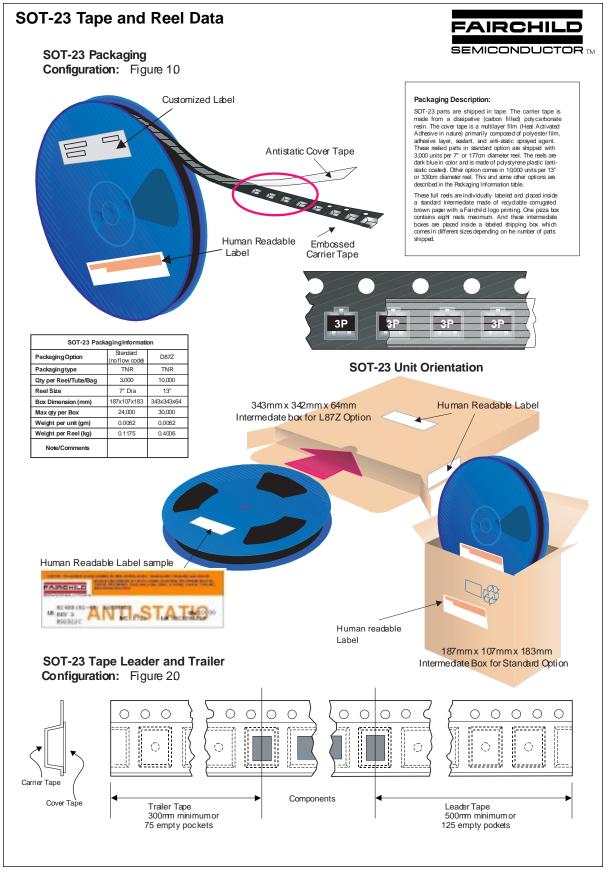
March 2001, Rev. B1





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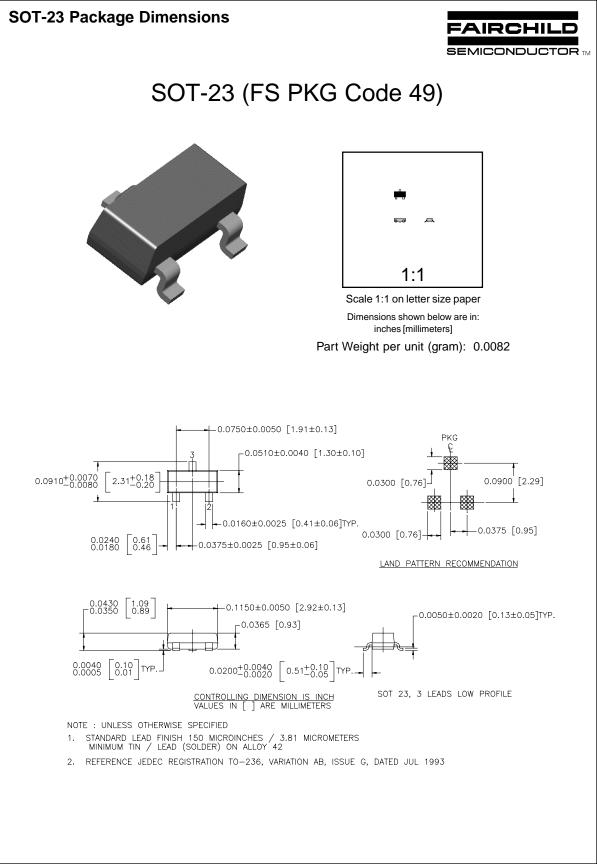


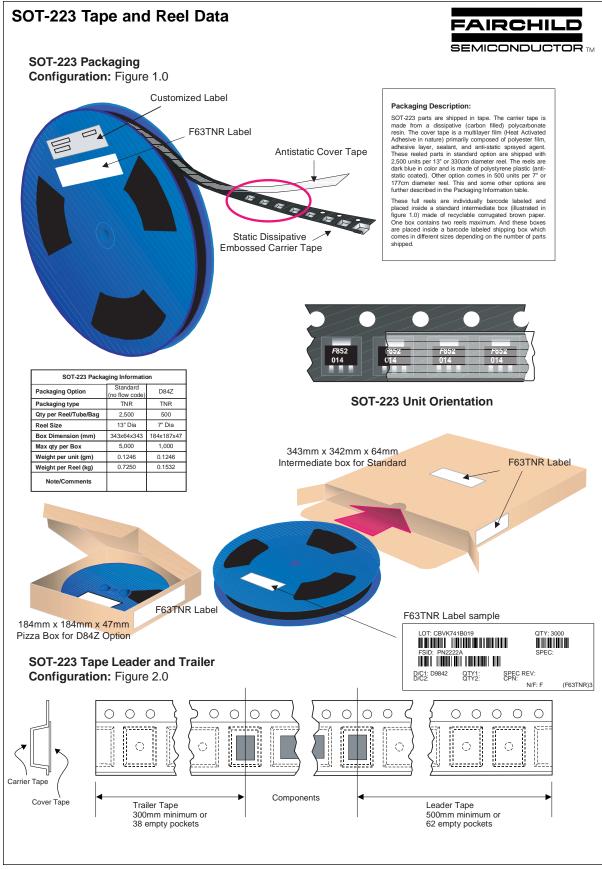
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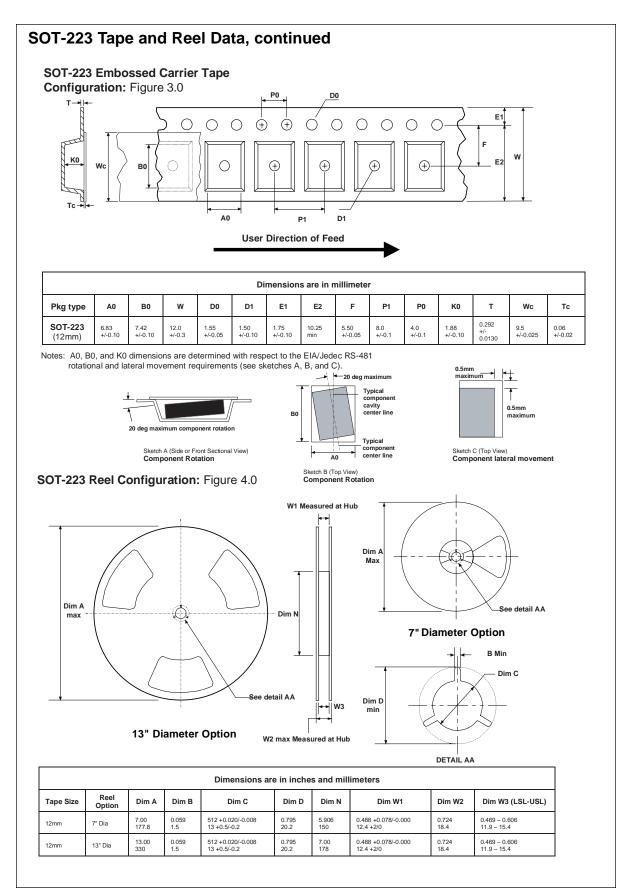
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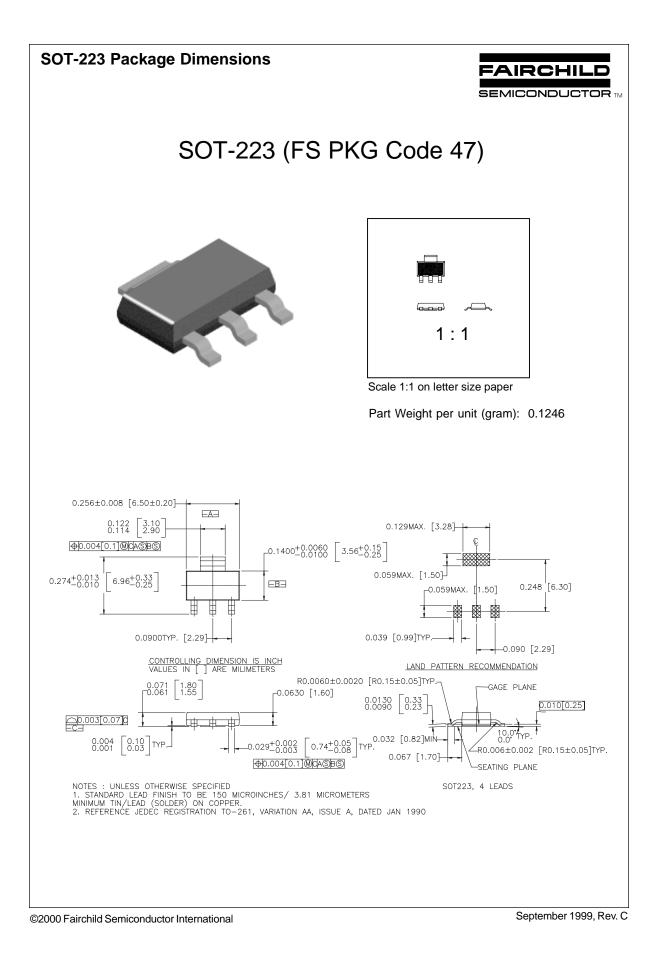




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